## Assignment 6

1) Distance between final lens and sample surface in SEM is called $\qquad$ WORKING DISTANCE
2) Smaller convergence angle of the electron beam in SEM leads to $\qquad$ Depth of Focus
smaller

- greater
- no change in

3) Which type of secondary electrons are produced by the back scattered electrons exiting the sample

- SEI
- SE II
- SE III

4) The electrons emitted after the beam interacts with the sample, having energy less than 50 eV is conventionally called as

- Auger electrons

Back scattered electrons
transmitted electrons

- Secondary electrons

5) As the Working distance in SEM decreases
resolution is better
Depth of Focus decreases
Magnification increases

- All of the above

6) Three dimentional kind of imaging is possible in SEM due to its
(1) SE and BSE electrons

- High depth of field

High magnification
High depth of focus
7) The qualitative and quantitative elemental analysis is done by collecting
back scattered electrons
X-rays form the surface of few nanometers thick
secondary electrons

- X-rays from depth of few microns

8) Misorientation across grain boundaries can be analysed by

- EBSD-orientation mapping

EDS-elemental mapping
EBSD-kikuchi patterns
BSE imaging
9) What is the advantage of WDS than EDS?
easy operation
has multiple detectors

- can even detect trace elements
can use high magnification

10) What source of diffractor is used in WDS and why?
(2) polymers to capture all wavelength of X-rays from organic and inorganic specimens

Organic crystals to enable high wavelength X -rays from elements with lower atomic number
silicon crystals to enable high and low wavelength X -rays
Quartz crystals to enable low wavelength X -rays from elements with higher atomic number

